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Docket No. 0756-1914

#26/E
4-27-03
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of) Art Unit: 2813
Shunpei YAMAZAKI et al.) Examiner: L. Schillinger
Serial No. 09/235,770)
Filed: January 25, 1999)
For: SEMICONDUCTOR DEVICE)
AND METHOD FOR FORMING)
THE SAME)

CERTIFICATE OF MAILING

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SUPPLEMENTAL AMENDMENT

Honorable Commissioner of Patents
Washington, D.C. 20231

Sir:

Further to the Amendment filed November 4, 2002, please amend the above-
identified application as follows:

IN THE CLAIMS:

Please amend claim 4 as follows:

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4. (Amended) A semiconductor device comprising:
a first insulating film comprising silicon nitride formed on a substrate;
a second insulating film comprising silicon oxide formed on said first
insulating film;
a semiconductor layer formed on said second insulating film wherein said
semiconductor layer includes at least source, drain and channel regions;
a third insulating film comprising silicon oxide formed on said
semiconductor layer wherein said third insulating film extends beyond edges of said
semiconductor layer so that said second and third insulating films are in direct contact to
each other;

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